

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

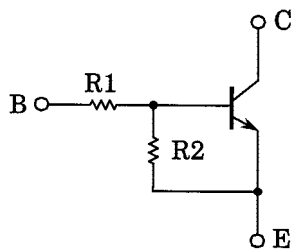
RN2301,RN2302,RN2303 RN2304,RN2305,RN2306

Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

Unit: mm

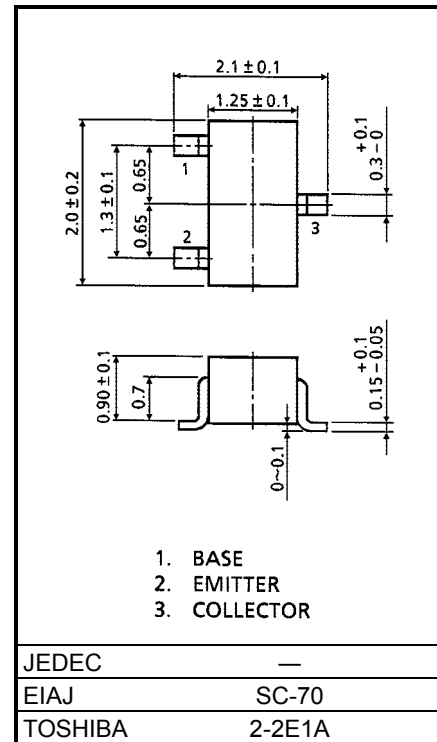
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1301~1306

Equivalent Circuit



Bias Resistor Values

Type No.	R1 (kΩ)	R2 (kΩ)
RN2301	4.7	4.7
RN2302	10	10
RN2303	22	22
RN2304	47	47
RN2305	2.2	47
RN2306	4.7	47



Weight: 0.006g

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-10	V
		-5	V
Collector current	I_C	-100	mA
Collector power dissipation	P_C	100	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2301~2306	I_{CBO}	—	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
		I_{CEO}	—	$V_{CE} = -50V, I_B = 0$	—	—	-500	
Emitter cut-off current	RN2301	I_{EBO}	—	$V_{EB} = -10V, I_C = 0$	-0.82	—	-1.52	mA
	RN2302		—		-0.38	—	-0.71	
	RN2303		—		-0.17	—	-0.33	
	RN2304		—		-0.082	—	-0.15	
	RN2305		—	$V_{EB} = -5V, I_C = 0$	-0.078	—	-0.145	
	RN2306		—		-0.074	—	-0.138	
DC current gain	RN2301	h_{FE}	—	$V_{CE} = -5V$ $I_C = -10mA$	30	—	—	—
	RN2302		—		50	—	—	
	RN2303		—		70	—	—	
	RN2304		—		80	—	—	
	RN2305		—		80	—	—	
	RN2306		—		80	—	—	
Collector-emitter saturation voltage	RN2301~2306	$V_{CE(sat)}$	—	$I_C = -5mA$ $I_B = -0.25mA$	—	-0.1	-0.3	V
Input voltage (ON)	RN2301	$V_{I(ON)}$	—	$V_{CE} = -0.2V$ $I_C = -5mA$	-1.1	—	-2.0	V
	RN2302		—		-1.2	—	-2.4	
	RN2303		—		-1.3	—	-3.0	
	RN2304		—		-1.5	—	-5.0	
	RN2305		—		-0.6	—	-1.1	
	RN2306		—		-0.7	—	-1.3	
Input voltage (OFF)	RN2301~2304	$V_{I(OFF)}$	—	$V_{CE} = -5V,$ $I_C = -0.1mA$	-1.0	—	-1.5	V
	RN2305, 2306		—		-0.5	—	-0.8	
Translation frequency	RN2301~2306	f_T	—	$V_{CE} = -10V,$ $I_C = -5mA$	—	200	—	MHz
Collector output capacitance	RN2301~2306	C_{ob}	—	$V_{CB} = -10V, I_E = 0$ $f = 1MHz$	—	3	6	pF
Input resistor	RN2301	R1	—	—	3.29	4.7	6.11	kΩ
	RN2302		—		7	10	13	
	RN2303		—		15.4	22	28.6	
	RN2304		—		32.9	47	61.1	
	RN2305		—		1.54	2.2	2.86	
	RN2306		—		3.29	4.7	6.11	
Resistor ratio	RN2301~2304	R1/R2	—	—	0.9	1.0	1.1	—
	RN2305		—		0.0421	0.0468	0.0515	
	RN2306		—		0.09	0.1	0.11	

